



BC807-16/-25/-40

45V PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC817)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

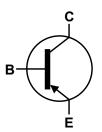
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight 0.008 grams (approximate)

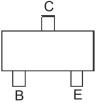


SOT23

Top View



Device Symbol



Top View Pin-Out

Ordering Information (Notes 5)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|----------------|------------|---------|--------------------|-----------------|-------------------|
| BC807-16-7-F | AEC-Q101 | K5A | 7 | 8 | 3,000 |
| BC807-25-7-F | AEC-Q101 | K5B | 7 | 8 | 3,000 |
| BC807-40-7-F | AEC-Q101 | K5C | 7 | 8 | 3,000 |
| BC807-40-13-F | AEC-Q101 | K5C | 13 | 8 | 10,000 |
| BC807-40Q-7-F | Automotive | K5C | 7 | 8 | 3,000 |
| BC807-40Q-13-F | Automotive | K5C | 13 | 8 | 10,000 |

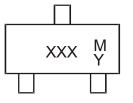
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/. 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



XXX = Product Type Marking Code (See table above) YM = Date Code Marking Y = Year ex: X = 2010 M = Month ex: 9 = September

Date Code Key

Notes:

| Year | 2010 | 20 | 011 | 2012 | 2 | 2013 | 2014 | | 2015 | 2016 | | 2017 |
|-------|------|-----|-----|------|-----|------|------|-----|------|------|-----|------|
| Code | Х | | Y | Z | | А | В | | С | D | | E |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | V |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Continuous Collector Current | I _C | -0.5 | A |
| Peak Collector Current | I _{CM} | -1.0 | A |
| Peak Base Current | I _{BM} | -200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|--|-------------------------------|----------------------------------|-------------|------|--|
| Power Dissipation | (Note 6) | D- | 310 | mW | |
| | ation (Note 7) P _D | | 350 | | |
| Thermal Resistance, Junction to Ambient | (Note 6) | | 403 | °C/W | |
| | (Note 7) | R _{0JA} | 357 | C/VV | |
| Thermal Resistance, Junction to Leads (Note 8) | | $R_{\theta JL}$ | 350 | °C/W | |
| Operating and Storage Temperature Range | | T _J ,T _{STG} | -55 to +150 | °C | |

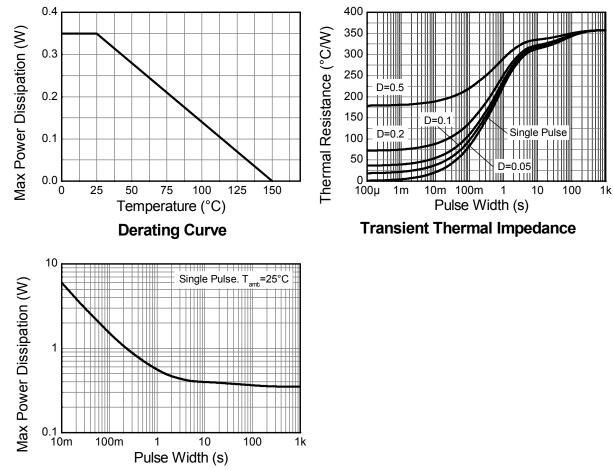
ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 8,000 | V | 3B |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | С |

6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; device Notes: neasured when operating in steady state condition.
Same as Note 6, except the device is mounted on 15mm X 15mm FR4 PCB.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



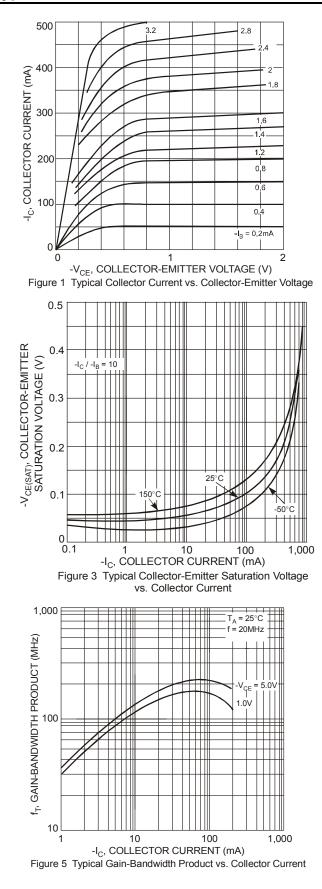
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

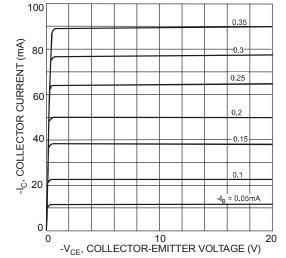
| Characteristic | | | Min | Тур | Max | Unit | Test Condition |
|-------------------------------------|----------------------------------|----------------------|-------------------|-----|-------------------|----------|---|
| Collector-Base Breakdown Voltage | | BV _{CBO} | -50 | _ | — | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage | | BV _{CEO} | -45 | _ | — | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | | BV _{EBO} | -5 | _ | — | V | I _C = -100μA |
| Collector-Emitter Cutoff Current | | ICES | _ | _ | -100 -5.0 | nA μA | V _{CE} = -45V V _{CE} = -25V, T _J = +150°C |
| Emitter-Base Cutoff Current | | I _{EBO} | _ | _ | -100 | nA | V _{EB} = -5.0V |
| DC Current Gain (Note 10) | BC807-16 BC807-25 BC807-40 | | 100 160 250 | | 250 400 600 | _ | V _{CE} = -1.0V, I _C = -100mA |
| | BC807-16 BC807-25 BC807-40 | h _{FE} | 60 100 170 | | _ | | V _{CE} = -1.0V, I _C = -300mA |
| Collector-Emitter Saturation Volta | age (Note 10) | V _{CE(SAT)} | | | -0.7 | V | I _C = -500mA, I _B = -50mA |
| Base-Emitter Voltage (Note 10) | | V _{BE} | | | -1.2 | V | V _{CE} = -1.0V, I _C = -300mA |
| Gain Bandwidth Product | | f⊤ | 100 | _ | _ | MHz | V _{CE} = -5.0V, I _C = -10mA, f = 50MHz |
| Collector-Base Capacitance | | | _ | _ | 12 | pF | V _{CB} = -10V, f = 1.0MHz |

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%

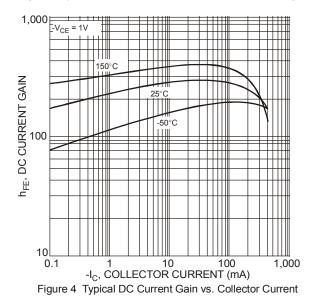


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





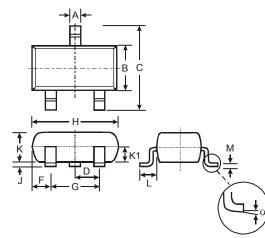






Package Outline Dimensions

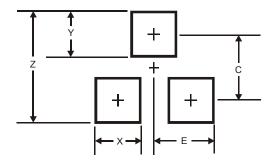
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23 | | | | | | |
|-------|--------|---------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| С | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| К | 0.903 | 1.10 | 1.00 | | | |
| K1 | - | - | 0.400 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| М | 0.085 | 0.18 | 0.11 | | | |
| α | 0° | 8° | - | | | |
| All | Dimens | ions in | mm | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Y | 0.9 |
| С | 2.0 |
| E | 1.35 |



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